## NSN 5961-01-413-1084

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Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic
Voltage Rating In Volts Per Characteristic:
32.0 working peak reverse voltage, peak total value
Power Rating Per Characteristic:
10.0 watts any acceptable preset
Special Features:
Peak pulse power dissipation at 25 degrees c., 15,000 w at 1 ms; maximum clamping v at 1 pp, 45 v; operating and storage temp -65 to
150 deg. C
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig: